

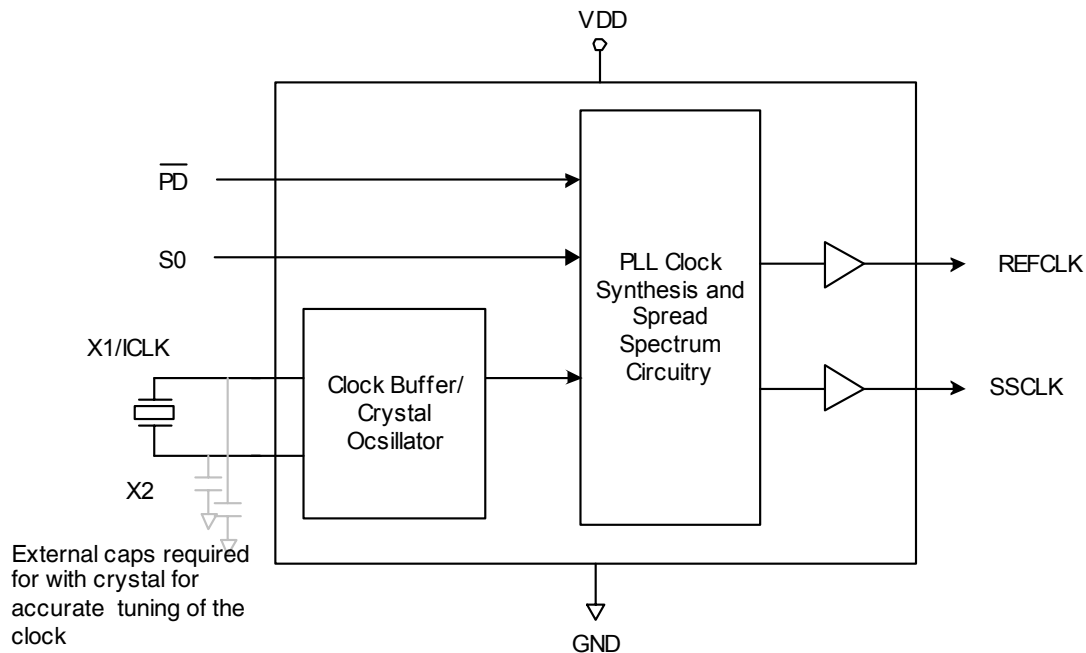
Description

The MK5818 generates a low EMI output clock and a reference clock from a clock or crystal input. The part is designed to lower EMI through the application of spreading a clock. Using IDT's proprietary mix of analog and digital Phase Locked Loop (PLL) technology, the device spreads the frequency spectrum of the output, reducing the frequency amplitude peaks by several dB depending on spread range. The MK5818 offers a range of down spread from a high speed clock or crystal input. The MK5818 generates one modulated (SSCLK) and unmodulated (REFCLK) clock and is compatible with Cypress CY25818. The modulated clock is controlled by the select pin, and the unmodulated clock has the same frequency as the input clock or crystal.

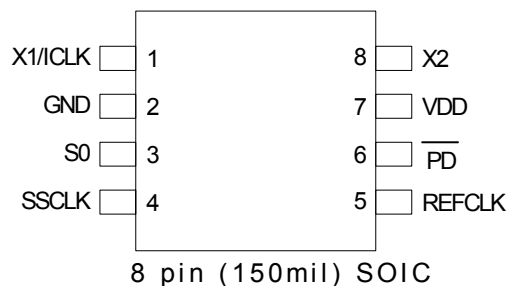
Features

- Packaged in 8-pin SOIC
- Input frequency range 8 to 16 MHz
- Provides modulated and unmodulated clocks
- Accepts a clock or crystal input
- Provides down spread modulation
- Provides power down function
- Reduce electromagnetic interference (EMI) by 8 to 16 db
- Operating voltage of 3.3 V
- Advanced, low-power CMOS process
- Pb (lead) free package, RoHS compliant

Block Diagram



Pin Assignment



Spread Percentage Select Table

S0	Spread Direction	Spread Percentage (%)
0	Down	-1.7
1	Down	-2.3
M	Down	-0.5

0 = connect to GND

M= unconnected

1 = connect directly to VDD

Pin Descriptions

Pin Number	Pin Name	Pin Type	Pin Description
1	X1/CLK	Input	Connect to 8-16 MHz crystal or clock.
2	GND	Power	Connect to ground.
3	S0	Input	Select spread percentage per table above. Tri-level input. Default = M.
4	SSCLK	Output	Spread spectrum clock output per table above.
5	REFCLK	Output	Unmodulated reference clock output.
6	$\overline{\text{PD}}$	Input	Power down tri-state. This pin powers down entire chip and tri-state the outputs when low. Internal pull-up.
7	VDD	Power	Connect to 3.3 V.
8	X2	Input	Connect to 8-16 MHz crystal or leave unconnected.

External Components

The MK5818 requires a minimum number of external components for proper operation.

Decoupling Capacitor

A decoupling capacitor of 0.01 μ F must be connected between VDD and GND, as close to these pins as possible. For optimum device performance, the decoupling capacitor should be mounted on the component side of the PCB. Avoid the use of vias in the decoupling circuit.

PCB Layout Recommendations

For optimum device performance and lowest output phase noise, the following guidelines should be observed.

1) The 0.01 μ F decoupling capacitor should be mounted on the component side of the board as close to the VDD pin as possible. No vias should be used between the decoupling capacitor and VDD pin. The PCB trace to VDD pin should be kept as short as possible, as should the PCB trace to the ground via.

2) An optimum layout is one with all components on the same side of the board, minimizing vias through other signal layers. Other signal traces should be routed away from the MK5818. This includes signal traces just underneath the device, or on layers adjacent to the ground plane layer used by the device.

Crystal Information

The crystal used should be a fundamental mode (do not use third overtone), parallel resonant. Crystal capacitors should be connected from pins X1 to ground and X2 to ground to optimize the initial accuracy. The value of these capacitors is given by the following equation:

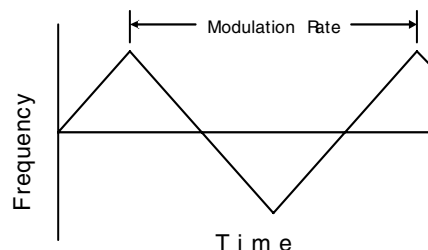
$$\text{Crystal caps (pF)} = (C_L - 6) \times 2$$

In the equation, C_L is the crystal load capacitance. So, for a crystal with a 16pF load capacitance, two 20 pF [(16-6) x 2] capacitors should be used.

Spread Spectrum Profile

The MK5818 low EMI clock generator uses an optimized frequency slew rate algorithm to facilitate down stream tracking of zero delay buffers and other PLL devices. The

frequency modulation amplitude is constant with variations of the input frequency.



Modulation Rate

The time required to transition from f_{MIN} (minimum frequency of the clock) to f_{MAX} (maximum frequency of the clock) and back to f_{MIN} is the period of the modulation rate, T_{MOD} . The modulation rates of spread spectrum clock generators are generally referred to in terms of frequency, and $f_{MOD} = 1/T_{MOD}$.

The input clock frequency (f_{IN}) and the internal divider determine the modulation rate.

The spread spectrum modulation rate (f_{MOD}) is given by the formula $f_{MOD} = f_{IN}/DR$, where:

f_{MOD} is the modulation rate, f_{IN} is the input frequency, and DR is the divider ratio (see table below).

Input Frequency Range	Divider Ratio (DR)
8 to 16 MHz	256

Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the MK5818. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Item	Rating
Supply Voltage, VDD	7 V
All Inputs and Outputs	-0.5 V to VDD+0.5 V
Ambient Operating Temperature	0 to +70° C
Storage Temperature	-65 to +150° C
Junction Temperature	125° C
Soldering Temperature	260° C

Recommended Operation Conditions

Parameter	Min.	Typ.	Max.	Units
Ambient Operating Temperature	0		+70	°C
Power Supply Voltage (measured in respect to GND)	+2.97		3.63	V

DC Electrical Characteristics

Unless stated otherwise, VDD = 3.3 V \pm 10%, Ambient Temperature 0 to +70° C

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Power Supply Range	V _{DD}		2.97	3.3	3.63	V
Input High Voltage	V _{INH}	S0 Input	0.85 V _{DD}	V _{DD}	V _{DD}	V
Input Middle Voltage	V _{INM}	S0 Input	0.40 V _{DD}	0.50 V _{DD}	0.60 V _{DD}	V
Input Low Voltage	V _{INL}	S0 Input	0.0	0.0	0.15 V _{DD}	V
Output High Voltage	V _{OH1}	I _{OH} =4 ma, SSCLK and REFCLK	2.4			V
Output High Voltage	V _{OH2}	I _{OH} =6 ma, SSCLK and REFCLK	2.0			V
Output Low Voltage	V _{OL1}	I _{OL} =4 ma, SSCLK			0.4	V
Output Low Voltage	V _{OL2}	I _{OL} =10 ma, SSCLK			1.2	V
Power Supply Current	I _{DD2}	F _{IN} = 8MHz, no load		10.0	12.5	mA
Power Supply Current	I _{DD3}	$\overline{\text{PD}}$ = GND		150	250	uA
Input Capacitance	C _{IN}			5		pF
Internal pull-up resistor	R _{PU}	SEL		360		k Ω

AC Electrical Characteristics

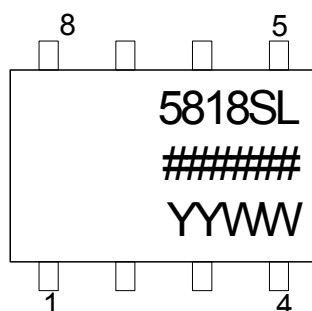
Unless stated otherwise, $V_{DD} = 3.3\text{ V} \pm 10\%$, Ambient Temperature 0 to $+70^{\circ}\text{ C}$ and $C_L = 15\text{ pF}$

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Input Clock Frequency			8		16	MHz
Output Clock Frequency			8		16	MHz
Clock Rise Time	trise1	SSCLK and REFCLK, 0.4 V to 2.4 V,	2.0	3.0	4.0	ns
Clock Fall Time	tfall1	SSCLK and REFCLK, 0.4 V to 2.4 V	2.0	3.0	4.0	ns
Input Clock Duty Cycle		X_1	20	50	80	%
Output Clock Duty Cycle		SSCLK and REFCLK @ 1.5V	45	50	55	%
Cycle to cycle Jitter		SSCLK, $F_{in} = F_{out} = 8\text{-}16\text{ MHz}$		250	350	ps
Cycle to cycle Jitter		REFCLK, $F_{in} = F_{out} = 8\text{-}16\text{ MHz}$		275	375	ps
EMI Peak Frequency Reduction				8 to 16		dB

Thermal Characteristics

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Thermal Resistance Junction to Ambient	θ_{JA}	Still air		110		°C/W
	θ_{JA}	1 m/s air flow		100		°C/W
	θ_{JA}	3 m/s air flow		80		°C/W
Thermal Resistance Junction to Case	θ_{JC}			35		°C/W

Marking Diagram (Pb free)

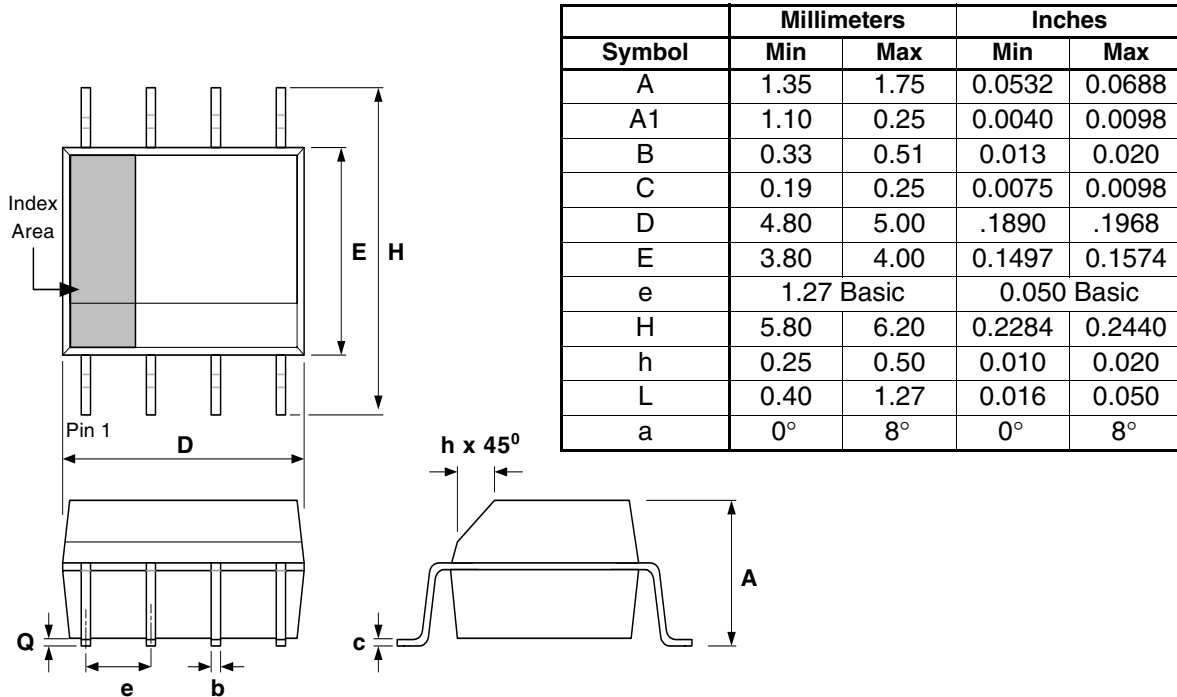


Notes:

1. ##### is the lot code.
2. YYWW is the last two digits of the year, and the week number that the part was assembled.
3. "L" or "LF" denotes Pb (lead) free package.
4. Bottom marking: country of origin if not USA.

Package Outline and Package Dimensions (8 pin SOIC, 150 Mil. Narrow Body)

Package dimensions are kept current with JEDEC Publication No. 95



Ordering Information

Part / Order Number	Marking	Shipping Packaging	Package	Temperature
MK5818SLF	see page 6	Tubes	8-pin SOIC	0 to +70° C
MK5818SLFTR		Tape and Reel	8-pin SOIC	0 to +70° C

"LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

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